

Features

- Metal silicon junction, majority carrier conduction
- The plastic carries Underwriters Laboraton Flammability Classification 94V-0
- Low reverse leakage
- High forward surge current capability
- High temperature soldering guaranteed:
250°C/10 seconds,0.375" (9.5mm)lead length ,
5 lbs(2.3kg)terminals



DO-15

Mechanical Date

- **Case:** JEDEC DO-15 molded plastic body
- **Terminals:** Plated axial leads,solderable per MIL-STD-750,Method 2026
- **Polarity :**Color band denotes cathode end
- **Mounting Position:** Any
- **Weight:**0.014 ounce, 0.40 grams

Major Ratings and Characteristics

$I_{F(AV)}$	2.0 A
V_{RRM}	20 V to 200 V
I_{FSM}	60 A
V_F	0.55~0.95
$T_j \text{ max.}$	150 °C

Maximum Ratings & Thermal Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.Single phase, half wave, 60HZ, resistive or inductive load.

For capacitive load, derate current by 20%.

Items	Symbols	SB 220	SB 230	SB 240	SB 250	SB 260	SB 270	SB 280	SB 290	SB 2100	SB 2150	SB 2200	UNIT									
Maximum repetitive peak reverse voltage	V_{RRM}	20	30	40	50	60	70	80	90	100	150	200	V									
Maximum RMS Voltage	V_{RMS}	14	21	28	35	42	49	56	63	70	105	140	V									
Maximum DC Blocking Voltage	V_{DC}	20	30	40	50	60	70	80	90	100	150	200	V									
Maximum Average Forward Rectified Current 0.375"(9.5mm)lead length (see fig.1)	$I_{(AV)}$	2.0											A									
Peak Forward Surge Current, 8.3ms single half-sine-wave superimposed on rated load (JEDEC method)	I_{FSM}	50											A									
Maximum instantaneous forward voltage at 2.0A	V_F	0.55		0.7		0.85				0.95			V									
Maximum DC reverse current $T_A=25^\circ\text{C}$ at rated DC blocking voltage $T_A=100^\circ\text{C}$	I_R	0.5						0.2				mA										
		10.0			5.0			2.0														
Typical junction capacitance NOTE 1	C_J	220		80									pF									
Typical thermal resistance NOTE2	$R_{\theta JA}$	50											°C/W									
Operating junction temperature range	T_J	−65 to +125				−65 to +150				°C												
Storage temperature range	T_{STG}	−65 to +150											°C									

TOTE:1.Measured at 1MHz and applied reverse voltage of 4.0V D.C.

2.Thermal resistance from junction tko ambient at 0.375"(9.5mm)lead length,P.C.B.mounted

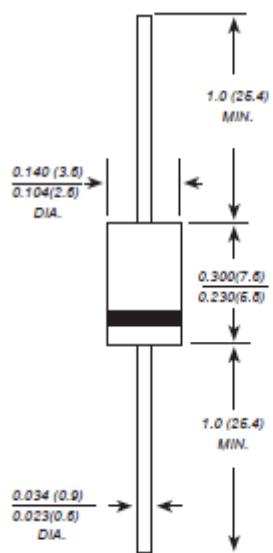
Package Outline**DO-15***Dimensions in inches and (millimeters)*

FIG. 1-FORWARD CURRENT DERATING CURVE

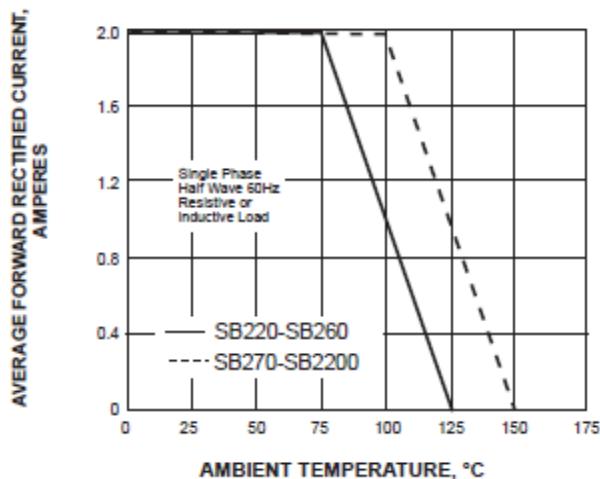


FIG. 2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

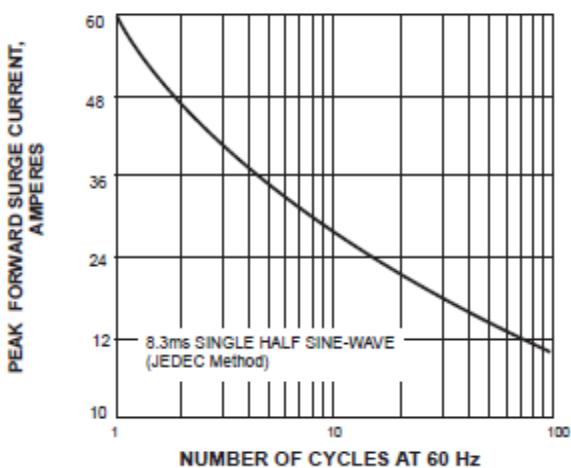


FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

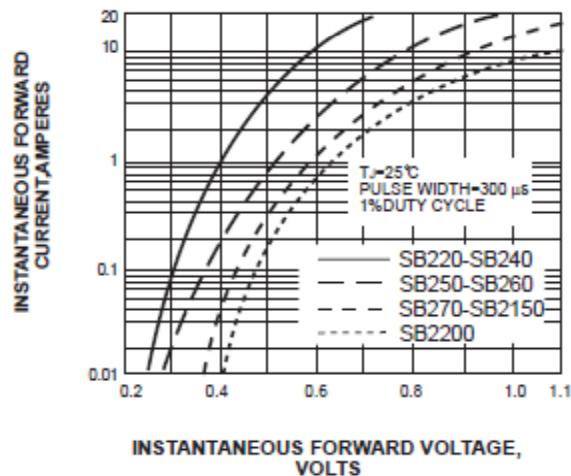


FIG. 4-TYPICAL REVERSE CHARACTERISTICS

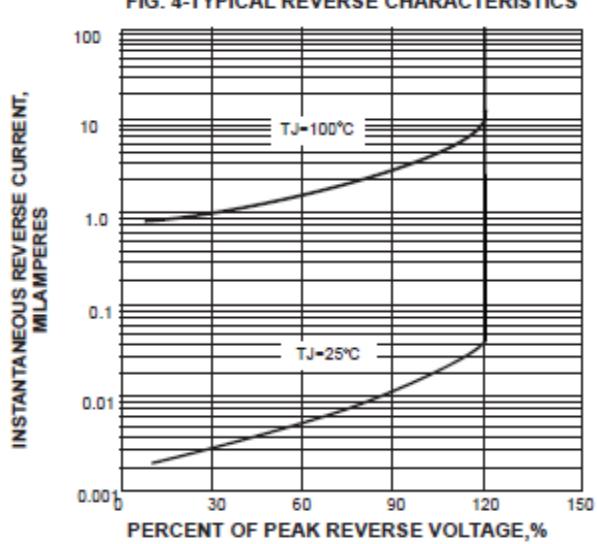


FIG. 5-TYPICAL JUNCTION CAPACITANCE

